

L Number	Hits	Search Text	DB	Time stamp
7	8	(("20020129191") or ("6622243") or ("5822565") or ("6145020") or ("6487464") or ("5909557") or ("20030033514") or ("20020138720")).PN.	USPAT; US-PGPUB	2004/05/11 16:37
-	5339	fram or feram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/10 12:31
-	191	(fram or feram) and (soc or system-on-chip or "system on a chip")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/10 12:33
-	193	(fram or feram) and (soc or system-on-chip or "system on a chip" or "system on chip" or system-on-a-chip)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/10 12:45
-	1672	ferroelectric and (soc or system-on-chip or "system on a chip" or "system on chip" or system-on-a-chip)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/10 12:45
-	1672	ferroelectric and (soc or system-on-chip or "system on a chip" or "system on chip" or system-on-a-chip)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/10 15:46
-	313	(ferroelectric and (soc or system-on-chip or "system on a chip" or "system on chip" or system-on-a-chip)) and (processor or microprocessor or cpu)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/10 13:12
-	667	(710/104).CCLS.	USPAT; US-PGPUB	2004/05/10 13:12
-	19508	fram or feram or ferroelectric	USPAT; US-PGPUB	2004/05/10 13:13
-	1	((710/104).CCLS.) and (fram or feram or ferroelectric)	USPAT; US-PGPUB	2004/05/10 13:14
-	1157	(710/305).CCLS.	USPAT; US-PGPUB	2004/05/10 13:14
-	0	("l8andl10").PN.	USPAT; US-PGPUB	2004/05/10 13:14
-	8	(fram or feram or ferroelectric) and ((710/305).CCLS.)	USPAT; US-PGPUB	2004/05/10 13:18
-	1284	(713/1).CCLS.	USPAT; US-PGPUB	2004/05/10 13:18
-	4	((713/1).CCLS.) and (fram or feram or ferroelectric)	USPAT; US-PGPUB	2004/05/10 13:22
-	1001	(713/2).CCLS.	USPAT; US-PGPUB	2004/05/10 13:22
-	3	(fram or feram or ferroelectric) and ((713/2).CCLS.)	USPAT; US-PGPUB	2004/05/10 13:23
-	749	(713/100).CCLS.	USPAT; US-PGPUB	2004/05/10 13:26
-	3	(fram or feram or ferroelectric) and ((713/100).CCLS.)	USPAT; US-PGPUB	2004/05/10 13:25
-	55246	(non-volatile or nonvolatile) adj memory	USPAT; US-PGPUB	2004/05/10 13:25
-	196	((713/100).CCLS.) and ((non-volatile or nonvolatile) adj memory)	USPAT; US-PGPUB	2004/05/10 15:32
-	1080	(710/100).CCLS.	USPAT; US-PGPUB	2004/05/10 15:32
-	4	((710/100).CCLS.) and (ferroelectric or feram or fram)	USPAT; US-PGPUB	2004/05/10 15:36
-	453	(711/104).CCLS.	USPAT; US-PGPUB	2004/05/10 15:33
-	20	((711/104).CCLS.) and (ferroelectric or feram or fram)	USPAT; US-PGPUB	2004/05/10 15:36

-	885	(710/107).CCLS.	USPAT; US-PGPUB	2004/05/10 15:36
-	1	((710/107).CCLS.) and (ferroelectric or feram or fram)	USPAT; US-PGPUB	2004/05/10 15:36
-	183970	soc or system-on-chip or "system on a chip" or "system on chip" or system-on-a-chip	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/10 18:15
-	28	(re-configur\$6 or reconfigur\$6) and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/10 18:15
-	644	(ferro-electric or ferroelectric or feram or fram) and (re-configur\$6 or reconfigur\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/11 11:39
-	4368	(ferro-electric or ferroelectric or feram or fram) and (re-configur\$6 or reconfigur\$6 or config\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/11 11:20
-	25	(ferro-electric or ferroelectric or feram or fram) near10 (re-configur\$6 or reconfigur\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/11 11:49
-	1	2003-459994.NRAN.	USPAT; DERWENT	2004/05/11 11:48
-	25	((ferro-electric or ferroelectric or feram or fram) near15 (re-configur\$6 or reconfigur\$6)) not 2003-459994.NRAN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/11 11:49
-	26	(ferro-electric or ferroelectric or feram or fram) near15 (re-configur\$6 or reconfigur\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/11 12:12
-	4	((ferro-electric or ferroelectric or feram or fram) adj embedded) near10 (re-configur\$6 or reconfigur\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/11 12:13